B.TECH/EE/3RD SEM/ELEC 2102/2023

ANALOG & DIGITAL ELECTRONICS (ELEC 2102)

Time Allotted : 2½ hrs

Figures out of the right margin indicate full marks.

Candidates are required to answer Group A and <u>any 4 (four)</u> from Group B to E, taking <u>one</u> from each group.

Candidates are required to give answer in their own words as far as practicable.

Group – A

1. Answer any twelve:

Choose the correct alternative for the following

(i) In a 4 variable K-map, a 2 variable product term is produced by (a) a 2 cell group of 1s (b) a 4 cell group of 1s (c) an 8 cell group of 1s (d) a 16 cell group of 1s. Minimum number of NAND gates required to realize an XOR gate is (ii) (a) 3 (b) 4 (c) 2(d) 5. A digital multiplexer is a combinational circuit that selects (iii) (a) many digital information and convert them into one (b) one digital information from several sources and transmits the selected one via a single output (c) many decimal inputs and transmits the selected information (d) many decimal outputs and accepts the selected information. (iv)An asynchronous sequential circuit is (a) a combinational circuit without feedback (b) a combinational circuit with feedback (c) one that uses a clock (d) none of the above. For a J-K flip flop, Q_n is the output at time step t_n. Which of the following Boolean (v) expression represents the characteristic equation for Q_{n+1} ? (b) $J\overline{Q_n} + \overline{K}Q_n$ (d) $JQ_n + \overline{K}\overline{Q_n}$. (a) $JQ_n + K\overline{Q_n}$ (c) $\overline{J}Q_n + K\overline{Q_n}$ (vi) Pin number 3 of IC 555 is called (a) output (b) control (c) threshold (d) ground. If the differential gain = 100 and CMRR = 100dB, then the common mode gain of (vii) a differential amplifier is (a) 0.001 (c) 0.1 (d) 1. (b) 0.01

Full Marks : 60

 $12 \times 1 = 12$

(viii)	The input impedance of a voltage series amplifier is given by		
	(a) $R_{iF} = R_i * (1 + A\beta)$	(b) $R_{iF} = R_i / (1 + A\beta)$	
	(c) $R_{iF} = R_i / A\beta$	(d) $R_{iF} = R_i * A\beta$.	

- (ix) The loop gain of a 3-stage RC phase shift oscillator should be (a) 1 (b) 2 (c) 3 (d) 29.
- (x) The output of an integrator circuit with square wave input is
 (a) Triangular wave
 (b) Impulse
 (c) Parabola
 (d) Step.

Fill in the blanks with the correct word

- (xi) 2's complement of the number $(1010101)_2$ is _____.
- (xii) The octal equivalent of the decimal number $(149)_{10}$ is _____.
- (xiii) The number of select lines required in a 32:1 multiplexer is ______.
- (xiv) The fundamental frequency of a crystal oscillator is ______ proportional to the thickness of the crystal.
- (xv) The first stage in the block diagram of an operational amplifier is a ______ input balanced output differential amplifier.

Group - B

2. (a) Model the linear differential equation using minimum number of operational amplifiers:

$$2\frac{d^2y}{dt^2} + \frac{dy}{dt} + 2y = 3$$

[(CO2)(Apply/IOCQ)]

(b) The transistor circuit shown in Fig.1 uses 5.3V Zener diode. Consider base to emitter voltage drop to be 0.6 V, determine the value of the current gain β.

[(CO1)(Apply/IOCQ)]



(c) Explain the working principle of the circuit shown in Fig.2. Also draw its transfer characteristics.

[(CO2)(Evaluate/HOCQ)]



 R_2

- 3. (a) Design a non- inverting adder circuit to obtain an output voltage V_0 where $V_0 = 2V_1 + 3V_2$ where V_1 and V_2 are the input voltages. [(CO2)(Apply/IOCQ)]
 - Calculate the values of I, I_Z and I_L for the circuit shown in Fig.3. It is given that (b) breakdown voltage of the zener diode is 5V, R = 1.5 k Ω and R_L = 1k Ω .

[(CO1) (Apply/IOCQ)]



Consider an inverting Schmitt trigger circuit as shown in Fig.4. If V_i = 20V (p-p), (c) 1kHz sine wave signal and V_{ref} = 3V, compute the upper and lower threshold voltages. Draw the output voltage waveform. Also compute the time duration of the positive and negative portion of the output voltage waveform. Consider $\pm V_{sat}$ = ±15V. [(CO2)(Evaluate/HOCQ)]



4 + 4 + 4 = 12

Group - C

- Derive the expression of oscillation frequency for the Wien bridge oscillator 4. (a) using an operational amplifier. Also determine the gain for sustained oscillation. [(CO3)(Apply/IOCQ)]
 - (b) State and explain Barkhausen criteria.

[(CO3)(Remember/LOCQ)] 8 + 4 = 12

- 5. (a) Discuss the principle of operation of an astable multivibrator using operational amplifier with the help of a neat circuit diagram. Sketch the output and capacitor voltage waveforms. Derive the expressions of time period of the output waveform and the duty cycle. [(CO3)(Analyse/IOCQ)] [(CO3)(Remember/LOCQ)]
 - (b) Draw the pin diagram of IC LM566.

8 + 4 = 12

Group - D

(a) Realize the following function using 2 input NAND gates only F = A + BC. 6. [(CO4)(Understand/LOCQ)]

- (b) Illustrate the design of a 8:1 multiplexer using 4:1 multiplexer. Use block diagram of the components. [(CO5)(Apply/IOCQ)]
- (c) Determine the canonical SOP form of the function Y=A+BC. [(CO4)(Create/HOCQ)]

4 + 5 + 3 = 12

7. (a) Implement the following Boolean expression using a 8×1 MUX: $F(A,B,C,D) = \Sigma_m (0,1,2,3,4,10,11,14,15)$ [(CO5)(Understand/LOCQ)]

(b) Apply the knowledge of K map to solve the following Boolean expression and implement the circuit using suitable logic gate. $F = \Sigma_m (1,5,6,12,13,14) + \Sigma_d (2,4)$ [(CO4)(Apply/IOCQ)]

(c) Design a single bit magnitude comparator circuit using NAND gate only.

[(CO5)(Create/HOCQ)]4 + 5 + 3 = 12

Group - E

8.	(a)	Describe the working of an \overline{S} - \overline{R} latch using NAND gates.	[(CO6)(Remember/LOCQ)]
	(b)	Construct a D flip-flop using J-K flip-flop.	[(CO6)(Apply/IOCQ)]
	(c)	Develop the characteristic equation of T flip flop.	[(CO6)(Create/HOCQ)]
			4 + 5 + 3 = 12

- 9. (a) Explain with necessary logic diagram the working of a 3 bit parallel in serial out (PISO) shift register. [(CO6)(Remember/LOCQ)]
 - (b) Design and implement a Mod-6 synchronous up counter using JK flip flop.

[(CO6) (Create/HOCQ)]6 + 6 = 12

Cognition Level	LOCQ	IOCQ	HOCQ
Percentage distribution	27.08	48.96	23.96

Course Outcome (CO):

After the completion of the course students will be able to

- 1. Recall basic principles of diodes, transistors and OPAMPs.
- 2. Understand basic principles of OPAMP based circuits for linear and nonlinear operations and analyze their implications.
- 3. Acquire knowledge about different waveform generators, 555 timers, ADCs and DACs and their applications.
- 4. Recall number systems and Boolean algebra.
- 5. Understand Boolean algebra based realisation of logic gates and design of various arithmetic and combinational circuits.
- 6. Design and analyze various sequential circuits like synchronous and asynchronous counters, shift registers using flip flops.

*LOCQ: Lower Order Cognitive Question; IOCQ: Intermediate Order Cognitive Question; HOCQ: Higher Order Cognitive Question.